imall

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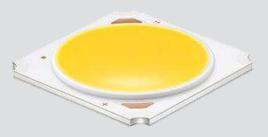
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High Voltage LED Series Chip on Board

LC033B



High efficacy COB LED package, well-suited for use in spotlight applications

Features & Benefits

- Chip on Board (COB) solution makes it easy to design in
- Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability
- Completed 6,000 hours of LM-80 Testing
- ENEC certified: Integral LED Module

Applications

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination







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1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	T _a	-40 ~ +105	°C	-
Storage Temperature	T _{stg}	-40 ~ +120	°C	_
LED Junction Temperature	Tj	150	°C	-
Case Temperature	Тс	105	°C	*Note
Forward Current	l _F	1620	mA	-
Power Dissipation	PD	59.9	W	_
ESD (HBM)	-	±2	kV	-
ESD (MM)	-	±0.5	kV	_

b) Electro-optical Characteristics ($I_F = 900 \text{ mA}, T_c = 25 \text{ °C}$)

ltem	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (VF)	V	YH	32.5	35.5	38.5
		3	70	-	-
Color Rendering Index (Ra)	-	5	80 (R9 > 0)	-	-
		7	90	-	-
Thermal Resistance (junction to chip point)	°C/W		_	0.9	-
Beam Angle	0		_	115	-
Working Voltage for Insulation	V				50
Nominal Power	W			32.0	
Eye Protection	0	Risk 1	-		-

Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ($T_j = T_c = T_a = 25$ °C)
- 2) Samsung maintains measurement tolerance of: forward voltage = ± 5 %, CRI = ± 1
- 3) Max Tc=105℃ (at max current) is for ENEC condition. Refer to the derating curve, '3. Typical Characteristics Graph' designed within the range.



c) Luminous Flux Characteristics (I_F = 900 mA)

CRI (R _a)	Nominal	Flux	Flux	Sorting ¹⁷ @1	「 _c = 25 °C (lm)	Calculated Flux ²⁾ @ ⁻	Γ _c = 85 °C (In
Min.	CCT (K)	Rank	Bin	Min.	Max.	Min.	Max.
	0000	40	41	4021	4570	3619	4113
	3000	4P	42	4570	5118	4113	4606
70	4000	40	41	4222	4798	3800	4318
70	4000	4P	42	4798	5374	4318	4836
	5000	40	41	4262	4844	3836	4359
	5000	4P	42	4844	5425	4359	4882
			38	3384	3659	3079	3330
		3P	39	3659	3934	3330	3580
	0700	38	40	3934	4210	3580	3831
	2700		41	4210	4485	3831	4081
		00	40	3934	4210	3580	3831
		3G	41	4210	4485	3831	4081
			38	3599	3892	3276	3542
		00	39	3892	4185	3542	3809
	2000	3P	40	4185	4478	3809	4075
	3000		41	4478	4771	4075	4342
		00	40	4185	4478	3809	4075
		3G	41	4478	4771	4075	4342
			38	3707	4009	3374	3648
		25	39	4009	4311	3648	3923
	0500	3P	40	4311	4613	3923	4198
	3500		41	4613	4915	4198	4472
			40	4311	4613	3923	4198
0.0		3G	41	4613	4915	4198	4472
80			38	3815	4126	3472	3755
			39	4126	4437	3755	4037
	4000	3P	40	4437	4747	4037	4320
	4000		41	4747	5058	4320	4603
		00	40	4437	4747	4037	4320
		3G	41	4747	5058	4320	4603
			38	3851	4165	3505	3790
		20	39	4165	4478	3790	4075
	5000	3P	40	4478	4792	4075	4361
	5000		41	4792	5105	4361	4646
		20	40	4478	4792	4075	4361
		3G	41	4792	5105	4361	4646
			38	3851	4165	3505	3790
		05	39	4165	4478	3790	4075
	6700	3P	40	4478	4792	4075	4361
	5700		41	4792	5105	4361	4646
		~~	40	4478	4792	4075	4361
		3G	41	4792	5105	4361	4646



c) Luminous Flux Characteristics (I_F = 900 mA)

CRI (R _a)	Nominal	Flux	Flux	Sorting ¹⁾ @ T	_c = 25 °C (lm)	Calculated Flux ²⁾	@ T _c = 85 °C (lm)
Min.	CCT (K)	Rank	Bin	Min.	Max.	Min.	Max.
			31	2963	3245	2696	2953
	2700	3P	32	3245	3527	2953	3210
			33	3527	3810	3210	3467
			31	3024	3312	2751	3013
	3000	3P	32	3312	3599	3013	3276
90			33	3599	3887	3276	3538
90			31	3114	3411	2834	3104
	3500	3P	32	3411	3707	3104	3374
			33	3707	4004	3374	3644
			31	3205	3510	2917	3194
	4000	3P	32	3510	3815	3194	3472
			33	3815	4121	3472	3750
	0700	0.1	31	2857	3175	2600	2889
	2700	3J	32	3175	3492	2889	3178
95	2000	0.1	31	2946	3273	2681	2978
	3000	3J	32	3273	3600	2978	3276
	0500	0.1	31	3034	3371	2761	3068
	3500	3J	32	3371	3708	3068	3375

Notes:

1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ($T_j = T_c = T_a = 25$ °C)

2) Calculated flux values are for reference only

3) Samsung maintains measurement tolerance of: luminous flux = ± 7 %, CRI = ± 1



2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S																	

Digit	PKG Information	Code				Specificat	tion
1 2 3	Samsung Package High Power	SPH					
4.5	Ostar	ww	Warm White	(T/U/V	//W Rank	s)	
4 5	Color	cw	Cool White ((Q/R F	Ranks)		
6	Product Version	1					
78	Form Factor	HD	СОВ				
9	Lens Type	N	No lens				
10	Internal Code	D	LC033				
11	Chip Type	2					
		3	Min. 70				
12	CRI & Sorting Temperature	5	Min. 80	°C			
		7	Min. 90	U			
		8	Min 95				
13 14	Forward Voltage (V)	YH	32.5~38.5				
		w	2700 K		WA,WB	(MacAdam Ellipse)	
		v	3000 K		VA, VB	(MacAdam Ellipse)	VW, VX, VY, VZ (ANSI bin)
15	CCT (K)	U	3500 K _{Bi}	in	UA, UB	(MacAdam Ellipse)	
15	001 (K)	т	4000 K ^{Cod}	de:	TA, TB	(MacAdam Ellipse)	TW, TX, TY, TZ (ANSI bin)
		R	5000 K		RA	(MacAdam Ellipse)	RW, RX, RY, RZ (ANSI bin)
		Q	5700 K				QW, QX, QY, QZ (ANSI bin)
		2	MacAdam 2-st	tep			
16	MacAdam / ANSI	3	MacAdam 3-st	tep			
		т	ANSI bin				
		ЗJ			31,32 (9	95 CRI)	
17 18	Luminous Flux	3P	Bi	in	31, 32, 33	(90 CRI); 38, 39, 40, 41	1 (80 CRI)
17 10		3G	Cod	de:	40, 41 (8	30 CRI)	
		4P			41,42 (7	70 CRI)	





a) Binning Structure (IF = 900 mA, T_c = 25 °C)

CRI (R _a) Min.	Nominal CCT (K)	Product Code	V _F Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ _v , Im)
	3000	SPHWW1HDND23YHVT4P	ΥH	VT	VW, VX	4P	41	4021 ~ 4570
	3000	3F11000111D10D23111014F		VI	VY, VZ	41	42	4570 ~ 5118
70	4000	SPHWW1HDND23YHTT4P	ΥH	Π	TW, TX	4P	41	4222 ~ 4798
70	4000	5PHWW1HDND231H114P	гп	11	TY, TZ	417	42	4798 ~ 5374
	5000	SPHCW1HDND23YHRT4P	YH	RT	RW, RX	4P	41	4262 ~ 4844
	5000	SFRGWINDIND23TRN14F	ТП	П	RY, RZ	46	42	4844 ~ 5425
							38	3384 ~ 3659
			VII	14/0	WB	20	39	3659 ~ 3934
		SPHWW1HDND25YHW23P	ΥH	W2	WB	3P	40	3934 ~ 4210
							41	4210 ~ 4485
							38	3384 ~ 3659
	0700		N/LL	14/0		0.5	39	3659 ~ 3934
	2700	SPHWW1HDND25YHW33P	ΥH	W3	WA, WB	3P	40	3934 ~ 4210
							41	4210 ~ 4485
							40	3934 ~ 4210
		SPHWW1HDND25YHW23G	ΥH	W2	WB	3G	41	4210 ~ 4485
						-	40	3934 ~ 4210
	SF	SPHWW1HDND25YHW33G	ΥH	W3	WA, WB	3G	41	4210 ~ 4485
							38	3599 ~ 3892
							39	3892 ~ 4185
		SPHWW1HDND25YHV23P	ΥH	V2	VB	3P	40	4185 ~ 4478
							41	4478 ~ 4771
80							38	3599 ~ 3892
							39	3892 ~ 4185
	3000	SPHWW1HDND25YHV33P	ΥH	V3	VA, VB	3P	40	4185 ~ 4478
							41	4478 ~ 4771
							40	4185 ~ 4478
		SPHWW1HDND25YHV23G	ΥH	V2	VB	3G	41	4478 ~ 4771
							40	4185 ~ 4478
		SPHWW1HDND25YHV33G	ΥH	V3	VA, VB	3G	41	4478 ~ 4771
							38	3707 ~ 4009
							39	4009 ~ 4311
		SPHWW1HDND25YHU23P	ΥH	U2	UB	3P	40	4311 ~ 4613
							41	4613 ~ 4915
	3500						38	3707 ~ 4009
							39	4009 ~ 4311
		SPHWW1HDND25YHU33P	ΥH	U3	UA, UB	3P	40	4311 ~ 4613
							40	4613 ~ 4915



a) Binning Structure (IF = 900 mA, T_c = 25 °C)

CRI (R _a) Min.	Nominal CCT (K)	Product Code	V _F Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ _v , Im)
			MIL	110		20	40	4311 ~ 4613
	3500	SPHWW1HDND25YHU23G	ΥH	U2	UB	3G	41	4613 ~ 4915
	3300	SPHWW1HDND25YHU33G	ΥH	U3	UA, UB	3G	40	4311 ~ 4613
		3FRWW1RDND231R033G	ГП	03	UA, UB	30	41	4613 ~ 4915
							38	3815 ~ 4126
		SPHWW1HDND25YHT23P	ΥH	T2	ТВ	3P	39	4126 ~ 4437
		3FNWWINDND23TN123F	ГП	12	ID	55	40	4437 ~ 4747
							41	4747 ~ 5058
							38	3815 ~ 4126
	4000	SPHWW1HDND25YHT33P	ΥH	Т3	TA, TB	3P	39	4126 ~ 4437
	4000	3FNWWINDND23TN133F	ГП	15	IA, ID	55	40	4437 ~ 4747
							41	4747 ~ 5058
		SPHWW1HDND25YHT23G	ΥH	T2	ТВ	20	40	4437 ~ 4747
		SPRWWIRDND23TRI23G	ΓΠ	ΙZ	ID	3G	41	4747 ~ 5058
		SPHWW1HDND25YHT33G	VII	то		20	40	4437 ~ 4747
		SPRWWIRDND2011133G	ΥH	Т3	TA, TB	3G	41	4747 ~ 5058
80							38	3851 ~ 4165
00			X11	DO		20	39	4165 ~ 4478
		SPHCW1HDND25YHR33P	ΥH	R3	RA	3P	40	4478 ~ 4792
							41	4792 ~ 5105
							38	3851 ~ 4165
	5000		X11	DT	RW, RX,	3P	39	4165 ~ 4478
	5000	SPHCW1HDND25YHRT3P	ΥH	RT	RY, RZ	38	40	4478 ~ 4792
							41	4792 ~ 5105
			N/L1		DA	00	40	4478 ~ 4792
		SPHCW1HDND25YHR33G	ΥH	R3	RA	3G	41	4792 ~ 5105
				DT	RW, RX,		40	4478 ~ 4792
		SPHCW1HDND25YHRT3G	ΥH	RT	RY, RZ	3G	41	4792 ~ 5105
							38	3851 ~ 4165
			X/II	OT	QW, QX	00	39	4165 ~ 4478
	E700	SPHCW1HDND25YHQT3P	ΥH	QT	QY, QZ	3P	40	4478 ~ 4792
	5700						41	4792 ~ 5105
			X/II	<u>от</u>	QW, QX	20	40	4478 ~ 4792
		SPHCW1HDND25YHQT3G	ΥH	QT	QY, QZ	3G	41	4792 ~ 5105

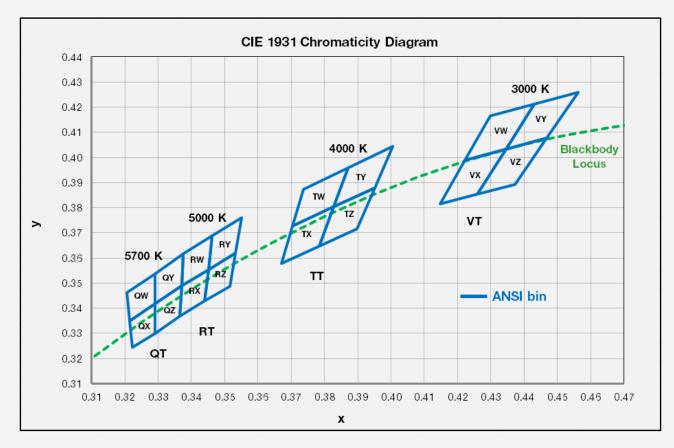


a) Binning Structure (IF = 900 mA, T_c = 25 °C)

CRI (R _a) Min.	Nominal CCT (K)	Product Code	V _F Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ _v , Im)
							31	2963 ~ 3245
		SPHWW1HDND27YHW23P	ΥH	W2	WB	3P	32	3245 ~ 3527
	0700						33	3527 ~ 3810
	2700						31	2963 ~ 3245
		SPHWW1HDND27YHW33P	ΥH	W3	WA, WB	3P	32	3245 ~ 3527
							33	3527 ~ 3810
							31	3024 ~ 3312
		SPHWW1HDND27YHV23P	ΥH	V2	VB	3P	32	3312 ~ 3599
	2000						33	3599 ~ 3887
	3000 -						31	3024 ~ 3312
		SPHWW1HDND27YHV33P	ΥH	V3	VA, VB	3P	32	3312 ~ 3599
00							33	3599 ~ 3887
90							31	3114 ~ 3411
		SPHWW1HDND27YHU23P	ΥH	U2	UB	3P	32	3411 ~ 3707
	0500						33	3707 ~ 4004
	3500						31	3114 ~ 3411
		SPHWW1HDND27YHU33P	ΥH	U3	UA, UB	3P	32	3411 ~ 3707
							33	3707 ~ 4004
							31	3205 ~ 3510
		SPHWW1HDND27YHT23P	ΥH	T2	ТВ	3P	32	3510 ~ 3815
	1000						33	3815 ~ 4121
	4000						31	3205 ~ 3510
		SPHWW1HDND27YHT33P	ΥH	Т3	ΤΑ, ΤΒ	3P	32	3510 ~ 3815
							33	3815 ~ 4121
			N/LL	14/0		0.1	31	2857 ~ 3175
	0700	SPHWW1HDND28YHW23J	ΥH	W2	WB	3J	32	3175 ~ 3492
	2700			14/0		0.1	31	2857 ~ 3175
		SPHWW1HDND28YHW33J	ΥH	W3	WA,WB	3J	32	3175 ~ 3492
			V/L1			0.1	31	2946 ~ 3273
05	5 3000	SPHWW1HDND28YHV23J	ΥH	V2	VB	3J	32	3273 ~ 3600
95			VU	1/0		01	31	2946 ~ 3273
		SPHWW1HDND28YHV33J	ΥH	V3	VA,VB	3J	32	3273 ~ 3600
			VU	110		21	31	3034 ~ 3371
	2500	SPHWW1HDND28YHU23J	YH	U2	UB	3J	32	3371 ~ 3708
	3500		VU	110		01	31	3034 ~ 3371
		SPHWW1HDND28YHU33J	ΥH	U3	UA,UB	ЗJ	32	3371 ~ 3708





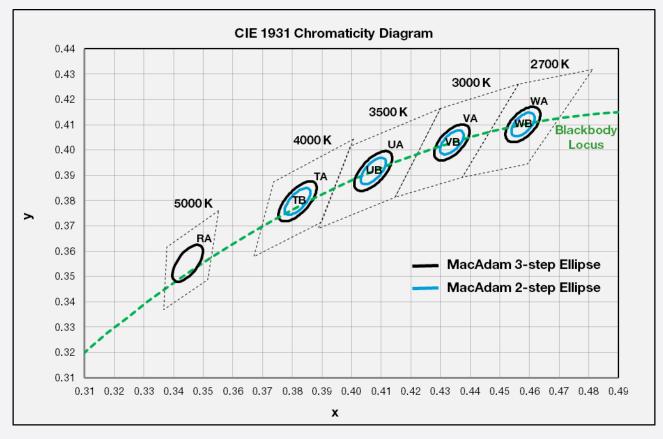


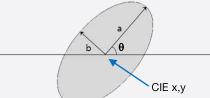
Region	CIE x	CIE y	Region	CIE x	CIE y						
	V rank (3000 K)										
	0.4223 0.3990 0.4345										
VW	0.4345	0.4033	VY	0.4468	0.4077						
VVV	0.4431	0.4213	VY	0.4562	0.4260						
	0.4299	0.4165		0.4431	0.4213						
	0.4223	0.3990		0.4260	0.3854						
104	0.4147	0.3814	1/7	0.4373	0.3893						
VX	0.4260	0.3854	VZ	0.4468	0.4077						
	0.4345	0.4033		0.4345	0.4033						
		R rank	(5000 K)								
	0.3376	0.3616		0.3463	0.3687						
DW	0.3463	0.3687	DV(0.3551	0.3760						
RW	0.3451	0.3554	RY	0.3533	0.3620						
	0.3371	0.3490	g 	0.3451	0.3554						
	0.3371	0.3490		0.3451	0.3554						
DV	0.3451	0.3554	07	0.3533	0.3620						
RX	0.3440	0.3428	RZ	0.3515	0.3487						
	0.3366	0.3369		0.3440	0.3428						

Region	CIE x	CIE y	Region	CIE x	CIE y						
	T rank (4000 K)										
	0.3736	0.3874		0.3871	0.3959						
714/	0.3871	0.3959	TV	0.4006	0.4044						
TW	0.3828	0.3803	TY	0.3952	0.3880						
	0.3703	0.3726		0.3828	0.3803						
	0.3703	0.3726		0.3828	0.3803						
TV	0.3828	0.3803		0.3952	0.3880						
ТХ	0.3784	0.3647	ΤΖ	0.3898	0.3716						
	0.3670	0.3578	4	0.3784	0.3647						
		Q rank	(5700 K)								
	0.3207	0.3462		0.3290	0.3538						
0144	0.3290	0.3538	01	0.3376	0.3616						
QW	0.3290	0.3417	QY	0.3371	0.3490						
	0.3215	0.3350		0.3290	0.3417						
	0.3215	0.3350		0.3290	0.3417						
0)/	0.3290	0.3417	07	0.3371	0.3490						
QX	0.3290	0.3300	QZ	0.3366	0.3369						
	0.3222	0.3243		0.3290	0.3300						









MacAdam Ellipse (WA, WB)								
Step	Step CIE x CIE y θ a b							
2-step	0.4578	0.4101	53.70	0.0054	0.0028			
3-step 0.4578 0.4101 53.70 0.0081 0.0042								

MacAdam Ellipse (UA, UB)							
Step CIE x CIE y θ a b							
2-step	0.4073	0.3917	54.00	0.0062	0.0028		
3-step	0.4073	0.3917	54.00	0.0093	0.0041		

	MacAdam Ellipse (RA)							
Step	CIE x			b				
3-step	0.3447	0.3553	59.62	0.0082	0.0035			

MacAdam Ellipse (VA, VB)								
Step CIE x CIE y θ a b								
0.4338	0.4030	53.22	0.0056	0.0027				
3-step 0.4338 0.4030 53.22 0.0083 0.0041								
	CIE x 0.4338	CIE x CIE y 0.4338 0.4030	CIE x CIE y θ 0.4338 0.4030 53.22	CIE x CIE y θ a 0.4338 0.4030 53.22 0.0056				

MacAdam Ellipse (TA, TB)							
Step CIE x CIE y θ a							
2-step	0.3818	0.3797	53.72	0.0063	0.0027		
3-step	0.3818	0.3797	53.72	0.0094	0.0040		

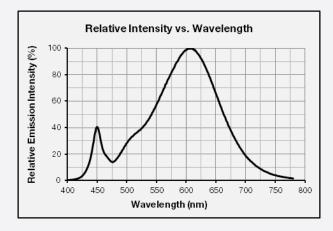
Note:

Samsung maintains measurement tolerance of: Cx, $Cy = \pm 0.005$



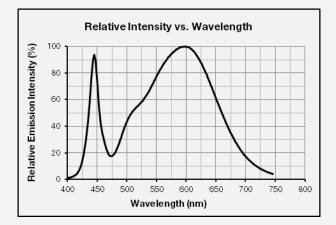
3. Typical Characteristics Graphs

a) Spectrum Distribution ($I_F = 900 \text{ mA}, T_c = 25 \text{ °C}$)

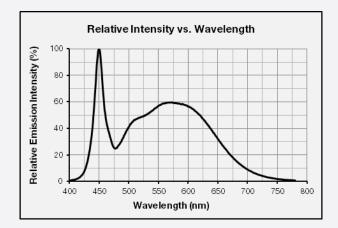


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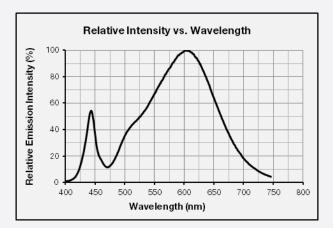
ССТ: 2700 К



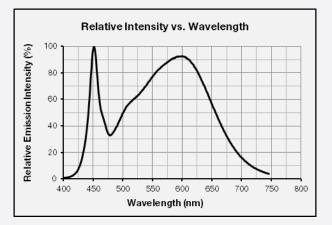




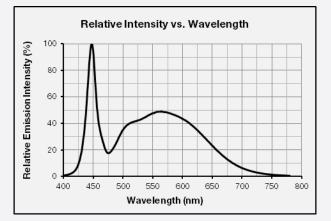




сст: 4000 к

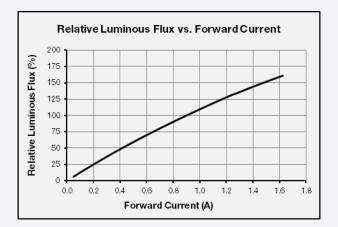


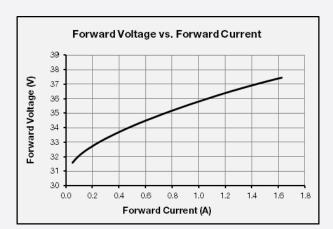




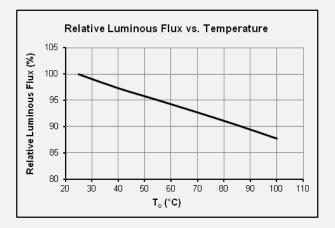






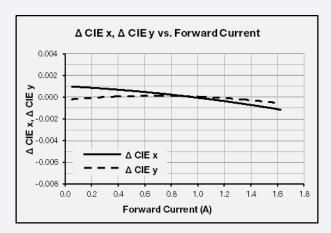


c) Temperature Characteristics (I_F = 900 mA)



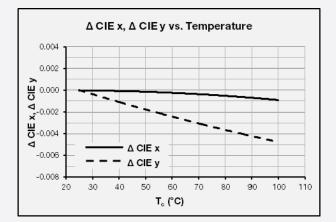


T_c = 25 °C



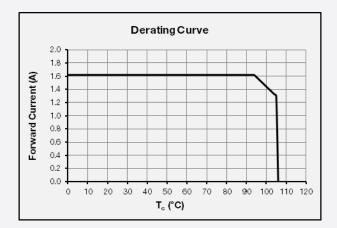
Forward Voltage vs. Temperature 36.5 36.0 Forward Voltage (V) 35.5 35.0 34.5 34.0 33.5 33.0 40 50 60 70 110 20 30 80 90 100 T_° (°C)



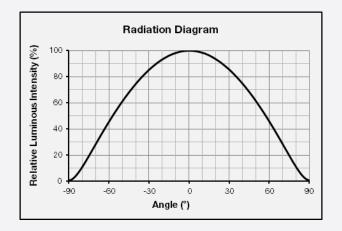




e) Derating Curve



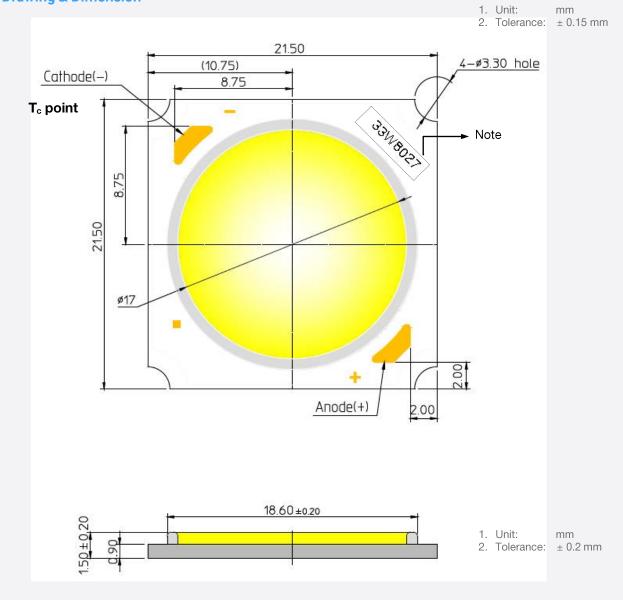
f) Beam Angle Characteristics (I_F = 900 mA, T_c = 25 °C)



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4. Outline Drawing & Dimension



ltem	Dimension	Tolerance	Unit
Length	21.50	±0.15	mm
Width	21.50	±0.15	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	17	±0.15	mm

Note: Denoted product information above is only an example (33W8027:33W, CRI80+, 2700K)



5. Reliability Test Items & Conditions

a) Test Items

Test Item	Test Condition	Test Hour / Cycle
Room Temperature Life Test	25 °C, I _F = max	1000 h
High Temperature Humidity Life Test	85 °C, 85 % RH, DC Derating, I _F = max	1000 h
High Temperature Life Test	105 °C, DC Derating, $I_F = max$	1000 h
Low Temperature Life Test	-40 °C, DC 1620 mA	1000 h
High Temperature Storage	120 °C	1000 h
Low Temperature Storage	-40 °C	1000 h
Thermal Shock	-45 °C / 15 min ↔ 125 °C / 15 min temperature change in 5 min	200 cycles
Temperature Cycle On/Off Test	-40 °C / 85 °C each 20 min, 100 min transfer power on/off each 5 min, DC 900 mA	100 cycles
Temperature Humidity Storage Test	-10 °C ↔ 25 °C, 95 % RH ↔ 85 °C, 95 % RH (24 h / cycle)	100 cycles
ESD (HBM)	R ₁ : 10 MΩ R ₂ : 1.5 kΩ C: 100 pF V: ±2 kV	5 times
ESD (MM)	R ₁ : 10 MΩ R ₂ : 0 kΩ C: 200 pF V: ±0.5 kV	5 times
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔ max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500 g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Salt Spray Test	35 °C, 5 % salt water 8 h spray, 16 h dwell	2 cycles

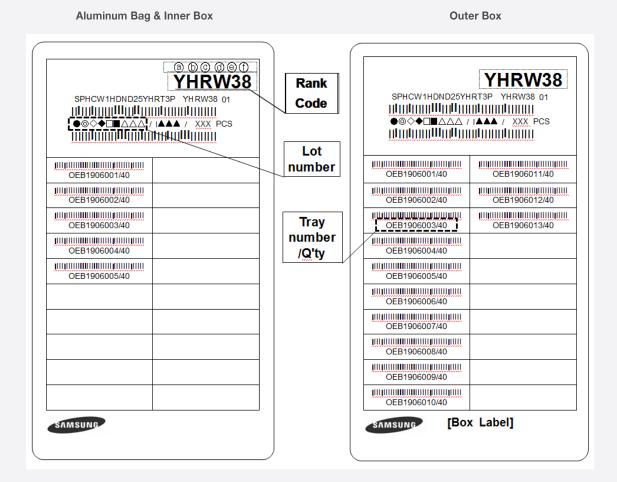
b) Criteria for Judging the Damage

ltem	Symbol	Test Condition	Limit		
item	Symbol	(T _c = 25 °C)	Min.	Max.	
Forward Voltage	VF	$I_F = 900 \text{ mA}$	L.S.L. * 0.9	U.S.L. * 1.1	
Luminous Flux	Φν	I _F = 900 mA	L.S.L * 0.7	U.S.L * 1.3	



6. Label Structure

a) Label Structure



Note: Denoted rank code and product code above is only an example (see description on page 5)

Rank Code:

- (a) Forward Voltage rank (refer to page 7-10)
- ©d: Chromaticity bin (refer to page 11-12)
- (e) f): Luminous Flux bin (refer to page 7-10)



b) Lot Number

The lot number is composed of the following characters:

$\bigcirc \bigcirc \diamondsuit \blacklozenge \square \blacksquare \triangle \triangle \triangle / 1 \blacktriangle \blacktriangle \triangle / xxx PCS$

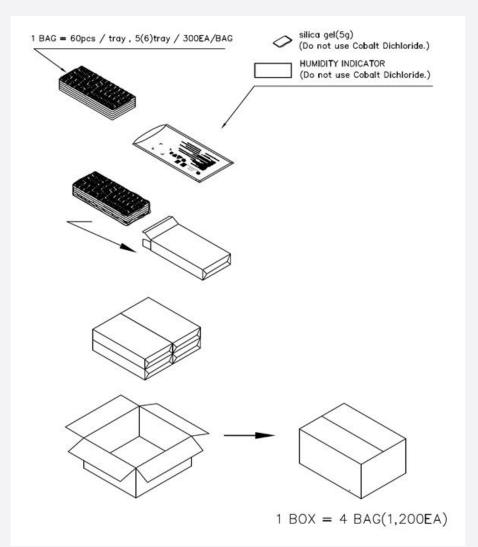
•	: Production site (S: Giheung, Korea, G: Tianjin, China)
\odot	: L (LED)
\diamond	: Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
•	: Year (Y: 2014, Z: 2015, A: 2016,)
	: Month (1~9, A, B, C)
	: Day (1~9, A, B~V)
$\triangle \triangle \triangle$: Product serial number (001 ~ 009)
	: Tray number (001 ~ 999)



7. Packing Structure

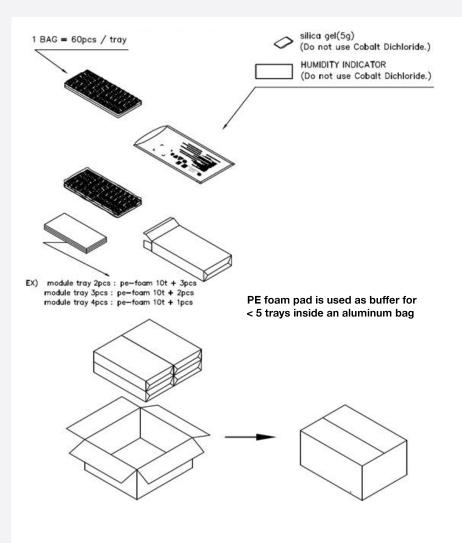
De alvina matarial	Max. quantity in pcs of COB	Dimension (mm)			
Packing material		Length	Width	Height	Tolerance
Tray	60	322.6	135.9	11	0.25
Aluminum Bag	300 (5 trays)	450	230	-	10
PE Foam Pad	-	280	130	10	2
Inner Box	300 (1 aluminum bag)	338	148	55	2
Outer Box	1200 (4 inner boxes)	351	308	120	5
Pallet	67,200 (56 outer boxes)	1000	1000	970	10

a) Packing Structure for 5 trays inside Aluminum Bag

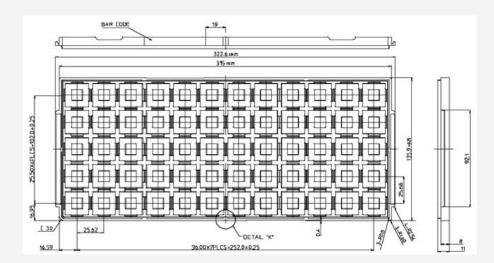




b) Packing Structure for <5 trays inside Aluminum Bag

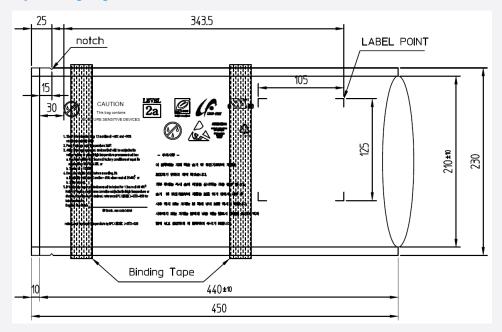


c) Tray





d) Aluminum Vinyl Packing Bag



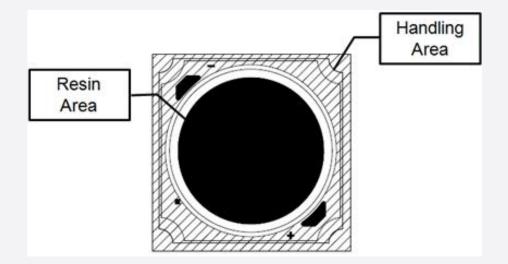
e) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Packing Bag





8. Precautions in Handling & Use

- This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 b. Stored at <10 % RH
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 6) Devices must be baked for 1 hour at 60 ± 5 °C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 8) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 9) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.





Legal and additional information.

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